



IMPORTANT NOTICE

10 December 2015

1. Global joint venture starts operations as WeEn Semiconductors

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WeEn Semiconductors



PHD13003C

NPN power transistor with integrated diode

Rev. 01 — 29 July 2010

Product data sheet

1. Product profile

1.1 General description

High voltage, high speed, planar passivated NPN power switching transistor with integrated anti-parallel emitter-collector diode in a SOT54 plastic package

1.2 Features and benefits

- Fast switching
- High typical DC current gain
- High voltage capability
- Integrated anti-parallel E-C diode

1.3 Applications

- Compact fluorescent lamps (CFL)
- Low power electronic lighting ballasts
- Off-line self-oscillating power supplies (SOPS) for battery charging

1.4 Quick reference data

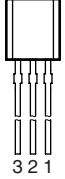
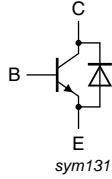
Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------------------|--------------------------------|--|-----|-----|-----|------|
| I_C | collector current | DC | - | - | 1.5 | A |
| P_{tot} | total power dissipation | $T_{lead} \leq 25\text{ °C}$; see Figure 1 | - | - | 2.1 | W |
| V_{CESM} | collector-emitter peak voltage | $V_{BE} = 0\text{ V}$ | - | - | 700 | V |
| Static characteristics | | | | | | |
| h_{FE} | DC current gain | $I_C = 0.5\text{ A}$; $V_{CE} = 2\text{ V}$; $T_j = 25\text{ °C}$ | 8 | 17 | 25 | |



2. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|--|---|
| 1 | B | base |  <p>SOT54 (TO-92)</p> |  |
| 2 | C | collector | | |
| 3 | E | emitter | | |

3. Ordering information

Table 3. Ordering information

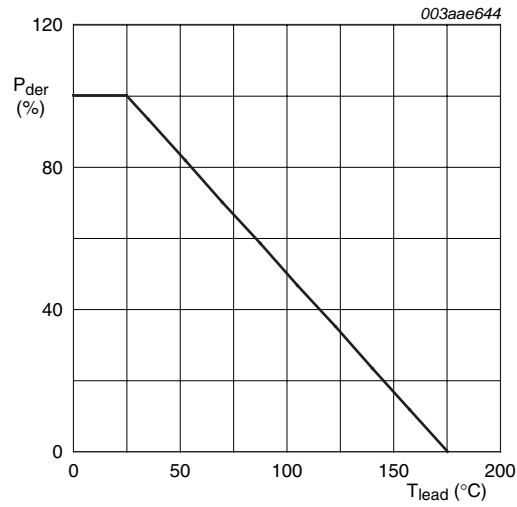
| Type number | Package | | |
|-------------|---------|---|---------|
| | Name | Description | Version |
| PHD13003C | TO-92 | plastic single-ended leaded (through hole) package; 3 leads | SOT54 |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------|--------------------------------|---|-----|------|------|
| V_{CESM} | collector-emitter peak voltage | $V_{BE} = 0\text{ V}$ | - | 700 | V |
| V_{CBO} | collector-base voltage | $I_E = 0\text{ A}$ | - | 700 | V |
| V_{CEO} | collector-emitter voltage | $I_B = 0\text{ A}$ | - | 400 | V |
| I_C | collector current | DC | - | 1.5 | A |
| I_{CM} | peak collector current | | - | 3 | A |
| I_B | base current | DC | - | 0.75 | A |
| I_{BM} | peak base current | | - | 1.5 | A |
| P_{tot} | total power dissipation | $T_{lead} \leq 25\text{ °C}$; see Figure 1 | - | 2.1 | W |
| T_{stg} | storage temperature | | -65 | 150 | °C |
| T_j | junction temperature | | - | 150 | °C |
| V_{EBO} | emitter-base voltage | $I_C = 0\text{ A}$; $I(\text{Emitter}) = 10\text{ mA}$ | - | 9 | V |



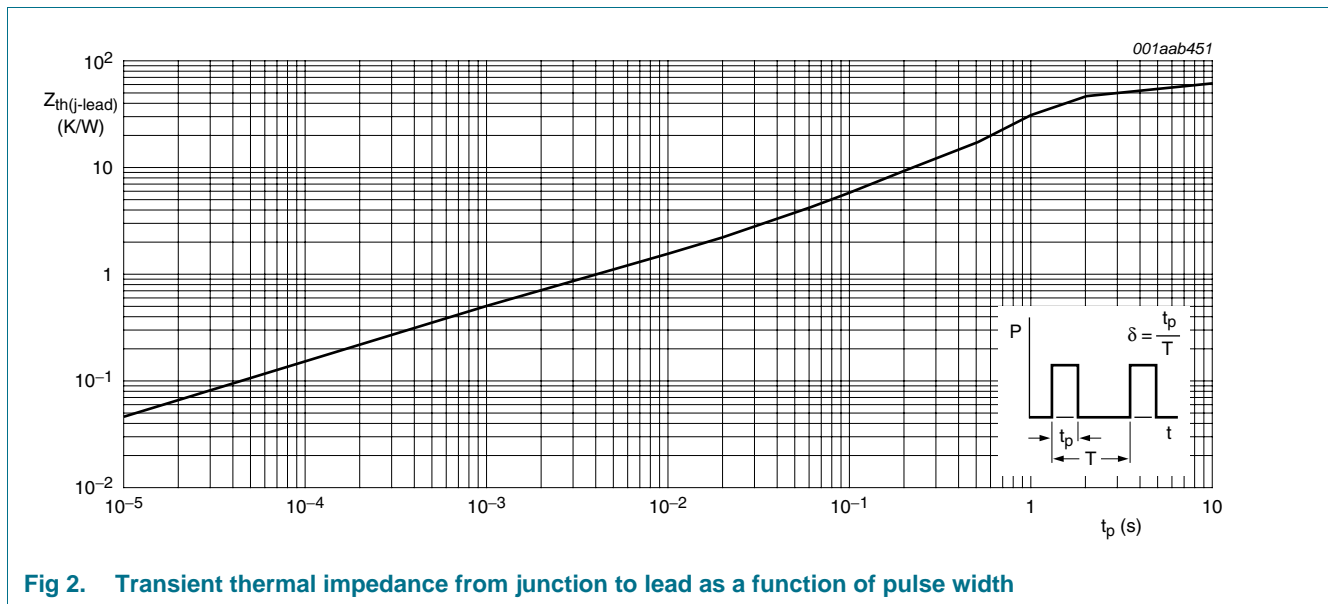
$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}\text{C})}} \times 100\%$$

Fig 1. Normalized total power dissipation as a function of lead temperature

5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------|---|--|-----|-----|-----|------|
| $R_{th(j-lead)}$ | thermal resistance from junction to lead | see Figure 2 | - | - | 60 | K/W |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air; printed-circuit board mounted; lead length = 4 mm | - | 150 | - | K/W |



6. Characteristics

Table 6. Characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|--------------------------------------|--|-----|-----|-----|---------------|
| Static characteristics | | | | | | |
| I_{CES} | collector-emitter cut-off current | $V_{BE} = 0\text{ V}; V_{CE} = 700\text{ V}$ | - | - | 1 | mA |
| | | $V_{BE} = 0\text{ V}; V_{CE} = 700\text{ V}; T_j = 100\text{ °C}$ | - | - | 5 | mA |
| I_{CEO} | collector-emitter cut-off current | $V_{CE} = 400\text{ V}; I_B = 0\text{ A}; T_{lead} = 25\text{ °C}$ | - | - | 0.1 | mA |
| I_{EBO} | emitter-base cut-off current | $V_{EB} = 9\text{ V}; I_C = 0\text{ A}; T_{lead} = 25\text{ °C}$ | - | - | 1 | mA |
| V_{CEOsus} | collector-emitter sustaining voltage | $I_B = 0\text{ A}; I_C = 1\text{ mA}; L_C = 25\text{ mH}; T_{lead} = 25\text{ °C};$ see Figure 3 ; see Figure 4 | 400 | - | - | V |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = 0.5\text{ A}; I_B = 0.1\text{ A}; T_{lead} = 25\text{ °C}$ | - | - | 0.5 | V |
| | | $I_C = 1\text{ A}; I_B = 0.25\text{ A}; T_{lead} = 25\text{ °C}$ | - | - | 1 | V |
| | | $I_C = 1.5\text{ A}; I_B = 0.5\text{ A}; T_{lead} = 25\text{ °C}$ | - | - | 1.5 | V |
| V_{BEsat} | base-emitter saturation voltage | $I_C = 0.5\text{ A}; I_B = 0.1\text{ A}; T_{lead} = 25\text{ °C}$ | - | - | 1 | V |
| | | $I_C = 1\text{ A}; I_B = 0.25\text{ A}; T_{lead} = 25\text{ °C}$ | - | - | 1.2 | V |
| V_F | forward voltage | $I_F = 0.5\text{ A}; T_j = 25\text{ °C}$ | - | - | 1.5 | V |
| h_{FE} | DC current gain | $I_C = 0.5\text{ A}; V_{CE} = 2\text{ V}; T_j = 25\text{ °C}$ | 8 | 17 | 25 | |
| | | $I_C = 1\text{ A}; V_{CE} = 2\text{ V}; T_j = 25\text{ °C}$ | 5 | 9 | 15 | |
| Dynamic characteristics | | | | | | |
| t_{on} | turn-on time | $I_C = 1\text{ A}; I_{Bon} = 0.2\text{ A}; I_{Boff} = -0.2\text{ A}; R_L = 75\text{ }\Omega; T_{lead} = 25\text{ °C};$ resistive load; see Figure 5 ; see Figure 6 | - | - | 1 | μs |
| t_s | storage time | $I_C = 1\text{ A}; I_{Bon} = 0.2\text{ A}; V_{BB} = -5\text{ V}; L_B = 1\text{ }\mu\text{H}; T_{lead} = 25\text{ °C};$ inductive load; see Figure 7 ; see Figure 8 | - | 0.8 | - | μs |
| | | $I_C = 1\text{ A}; I_{Bon} = 0.2\text{ A}; I_{Boff} = -0.2\text{ A}; R_L = 75\text{ }\Omega; T_{lead} = 25\text{ °C};$ resistive load; see Figure 5 ; see Figure 6 | - | - | 0.7 | μs |
| t_f | fall time | $I_C = 0.5\text{ A}; I_{Bon} = 0.1\text{ A}; V_{BB} = -5\text{ V}; L_B = 1\text{ }\mu\text{H}; T_{lead} = 25\text{ °C};$ inductive load; see Figure 7 ; see Figure 8 | - | 0.1 | - | μs |
| | | $I_C = 1\text{ A}; I_{Bon} = 0.2\text{ A}; I_{Boff} = -0.2\text{ A}; R_L = 75\text{ }\Omega; T_{lead} = 25\text{ °C};$ resistive load; see Figure 5 ; see Figure 6 | - | - | 0.7 | μs |

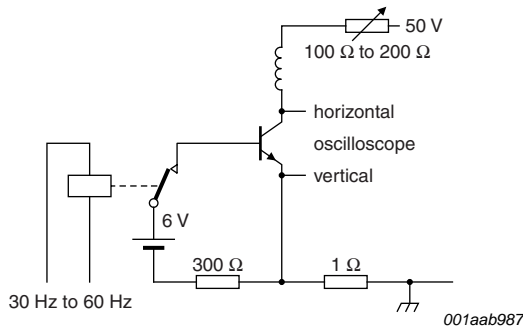


Fig 3. Test circuit for collector-emitter sustaining voltage

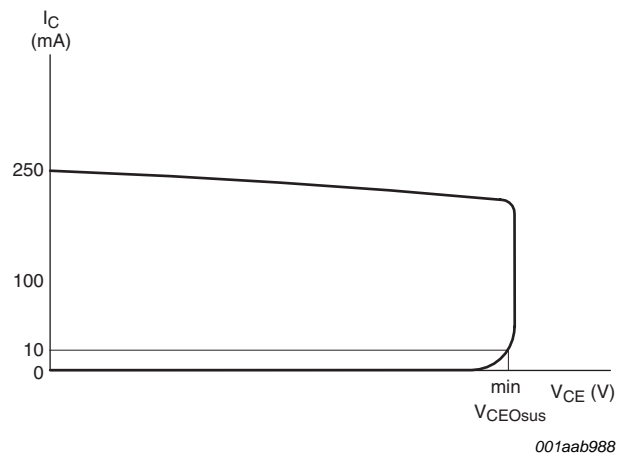
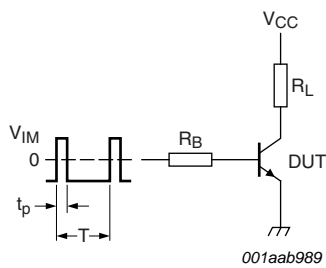


Fig 4. Oscilloscope display for collector-emitter sustaining voltage test waveform



$V_{IM} = -6 \text{ to } +8 \text{ V}; V_{CC} = 250 \text{ V}; t_p = 20 \mu\text{s}; \delta = \frac{t_p}{T} = 0.01$
 R_B and R_L calculated from I_{Con} and I_{Bon} requirements.

Fig 5. Test circuit for resistive load switching

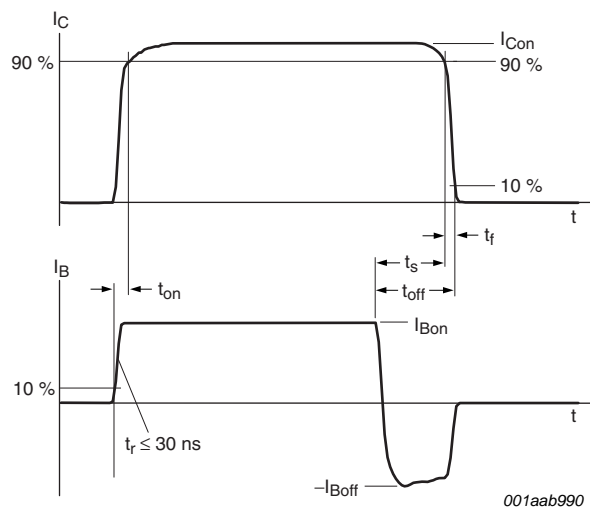
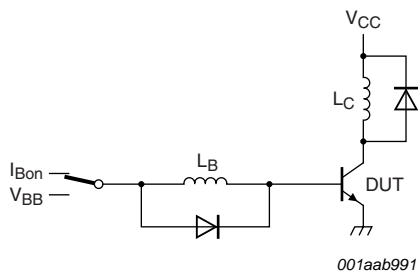


Fig 6. Switching times waveforms for resistive load



$V_{CC} = 300\text{ V}; V_{BB} = -5\text{ V}; L_C = 200\ \mu\text{H}; L_B = 1\ \mu\text{H}$

Fig 7. Test circuit for inductive load switching

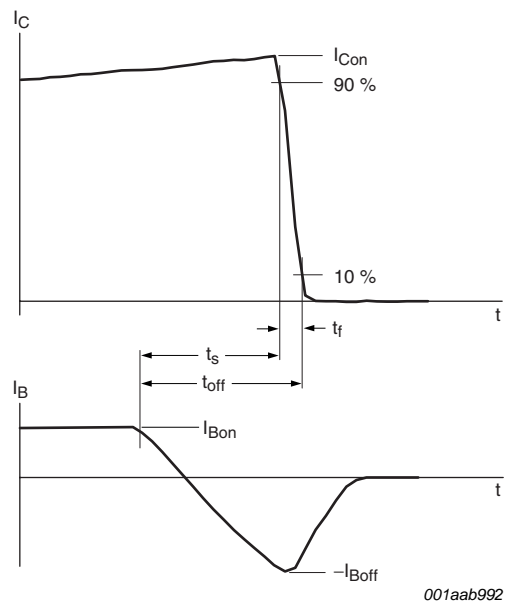


Fig 8. Switching times waveforms for inductive load

7. Package outline

Plastic single-ended leaded (through hole) package; 3 leads

SOT54

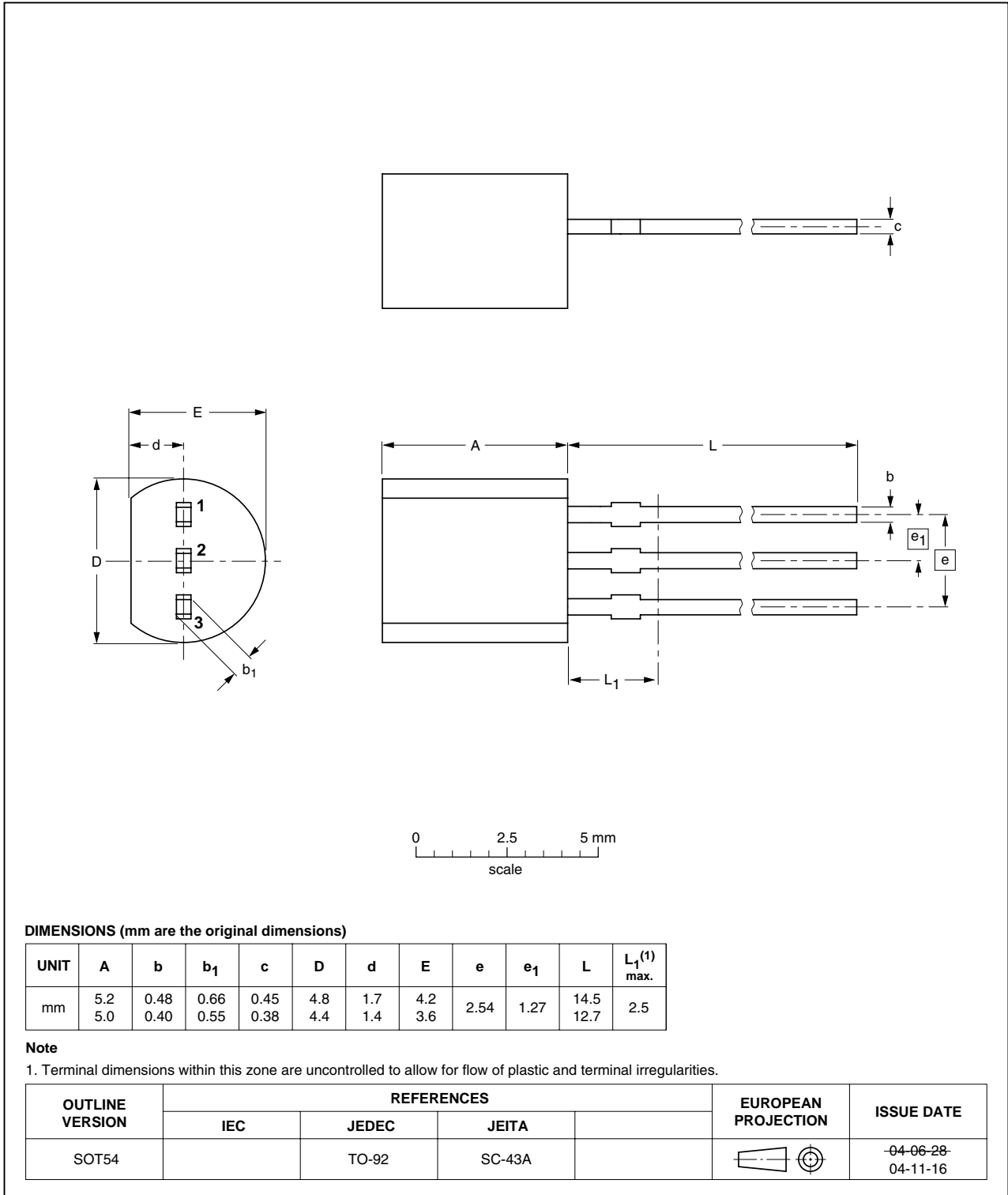


Fig 9. Package outline SOT54 (TO-92)

8. Revision history

Table 7. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|---------------|--------------|--------------------|---------------|------------|
| PHD13003C v.1 | 20100729 | Product data sheet | - | - |

9. Legal information

9.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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11. Contents

| | | |
|-----------|--|-----------|
| 1 | Product profile | 1 |
| 1.1 | General description | 1 |
| 1.2 | Features and benefits | 1 |
| 1.3 | Applications | 1 |
| 1.4 | Quick reference data | 1 |
| 2 | Pinning information | 2 |
| 3 | Ordering information | 2 |
| 4 | Limiting values | 2 |
| 5 | Thermal characteristics | 4 |
| 6 | Characteristics | 5 |
| 7 | Package outline | 8 |
| 8 | Revision history | 9 |
| 9 | Legal information | 10 |
| 9.1 | Data sheet status | 10 |
| 9.2 | Definitions | 10 |
| 9.3 | Disclaimers | 10 |
| 9.4 | Trademarks | 11 |
| 10 | Contact information | 11 |

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